

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1 – 50 (Canceled)

51. (New) A light emitting device comprising:  
a light emitting layer comprising an organic material,  
wherein said light emitting layer contains oxygen at a concentration equal to or less than  $1 \times 10^{19} \text{ cm}^{-3}$ .
52. (New) The light emitting device according to claim 1 wherein said light emitting layer comprises tris-8-quinolinolate aluminum complex ( $\text{Alq}_3$ ).
53. (New) A light emitting device comprising:  
a substrate;  
an insulating film comprising silicon nitride over the substrate; and  
a light emitting layer comprising an organic material formed over the insulating film,  
wherein said light emitting layer contains oxygen at a concentration equal to or less than  $1 \times 10^{19} \text{ cm}^{-3}$ .
54. (New) The light emitting device according to claim 3 wherein said light emitting layer comprises tris-8-quinolinolate aluminum complex ( $\text{Alq}_3$ ).

55. (New) The light emitting device according to claim 3 further comprising a thin film transistor formed over the substrate and below said insulating film.
56. (New) A light emitting device comprising:  
a substrate;  
an insulating film comprising silicon nitride over the substrate;  
an anode formed on said insulating film;  
a light emitting layer comprising an organic material formed over the anode; and  
a cathode formed over the light emitting layer,  
wherein said light emitting layer contains oxygen at a concentration equal to or less than  $1 \times 10^{19} \text{ cm}^{-3}$ .
57. (New) The light emitting device according to claim 6 wherein said light emitting layer comprises tris-8-quinolinolate aluminum complex ( $\text{Alq}_3$ ).
58. (New) The light emitting device according to claim 7 further comprising a thin film transistor formed over the substrate and electrically connected to said anode.
59. (New) A light emitting device comprising:  
a substrate;  
a light emitting layer comprising an organic material formed over the substrate;  
and  
an insulating film comprising carbon formed over the light emitting layer,  
wherein said light emitting layer contains oxygen at a concentration equal to or less than  $1 \times 10^{19} \text{ cm}^{-3}$ .
60. (New) The light emitting device according to claim 9 wherein said insulating film comprises diamond like carbon.

61. (New) The light emitting device according to claim 9 wherein said light emitting layer comprises tris-8-quinolinolate aluminum complex ( $\text{Alq}_3$ ).

62. (New) The light emitting device according to claim 9 further comprising a thin film transistor formed over the substrate and electrically connected to said anode.

63. (New) A light emitting device comprising:

a substrate;

an insulating film comprising silicon oxynitride over the substrate; and

a light emitting layer comprising an organic material formed over the insulating film,

wherein said light emitting layer contains oxygen at a concentration equal to or less than  $1 \times 10^{19} \text{ cm}^{-3}$ .

64. (New) The light emitting device according to claim 13 wherein said light emitting layer comprises tris-8-quinolinolate aluminum complex ( $\text{Alq}_3$ ).

65. (New) The light emitting device according to claim 13 further comprising a thin film transistor formed over the substrate and below said insulating film.

66. (New) A light emitting device comprising:

a hole injecting layer comprising an organic material,

wherein said hole injecting layer contains oxygen at a concentration equal to or less than  $1 \times 10^{19} \text{ cm}^{-3}$ .

67. (New) The light emitting device according to claim 16 wherein said organic material is phthalocyanine-based organic compound.

68. (New) The light emitting device according to claim 16 wherein said device is an active matrix type device.

69. (New) A light emitting device comprising:  
a hole transporting layer comprising an organic material,  
wherein said hole injecting layer contains oxygen at a concentration equal to or less than  $1 \times 10^{19} \text{cm}^{-3}$ .

70. (New) The light emitting device according to claim 19 wherein said organic material is aromatic amine-based organic compound.

71. (New) The light emitting device according to claim 19 wherein said device is an active matrix type device.